## High Voltage LED Series Chip on Board

# LCo26D-Gen.1



# High efficacy COB LED package well-suited for use in spotlight applications









#### **Features & Benefits**

- Chip on Board (COB) solution makes it easy to design in
- · Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability

#### **Applications**

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination



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#### 1. Characteristics

#### a) Absolute Maximum Rating

ltem	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	Ta	-40 ~ +105	°C	-
Storage Temperature	$T_{stg}$	-40 ~ +120	°C	-
LED Junction Temperature	TJ	140	°C	-
Case Temperature	Tc	105	°C	
Forward Current	l <sub>F</sub>	1840	mA	-
Power Dissipation	$P_{D}$	69	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	-	±0.5	kV	-

#### b) Electro-optical Characteristics ( $I_F = 720 \text{ mA}, T_J = 85 \text{ }^{\circ}\text{C}$ )

ltem	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (V <sub>F</sub> )	V	YZ	31.8	34.6	37.5
Color Decidering Index (D.)		5	80	-	-
Color Rendering Index (R <sub>a</sub> )	-	7	90	-	
Thermal Resistance (junction to chip point)	°C/W		-	1.0	-
Beam Angle	0		-	115	-
Nominal Power	W			24.9	

#### Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ( $T_J = T_C = T_a = 85$  °C)
- 2) Samsung maintains measurement tolerance of: forward voltage =  $\pm 5$  %, CRI =  $\pm 1$
- 3) Refer to the derating curve, '3. Typical Characteristics Graph' designed within the range.

#### c) Luminous Flux Characteristics ( $I_F = 720 \text{ mA}$ )

CRI (R <sub>a</sub> )	Nominal	Flux		Flux @ T <sub>c</sub> = 85 °C (	lm)
Min.	CCT (K)	Rank	Min.	Тур.	Max.
	2700	K0	3064	3225	-
	2700 "	D1	3225	3386	-
	2000	K2	3220	3389	-
	3000	D1	3389	3558	-
	3500	K3	3314	3488	-
		D1	3488	3663	-
80	4000	K3	3380	3558	-
ou ou	4000	D1	3558	3736	-
	5000	K4	3409	3588	-
	5000	D1	3588	3767	-
	5700	K4	3409	3588	-
	5700 "	D1	3588	3767	-
	6500	K3	3380	3558	-
		D1	3558	3736	-

CRI (R <sub>a</sub> )	Nominal	Flux		Flux @ T <sub>c</sub> = 85 °C (Im)		
Min.	CCT (K)	Rank	Min.	Тур.	Max.	
	2700	J6	2622	2760	-	
	2700	D1	2760	2898	-	
	3000	J7	2758	2903	-	
	3000	D1	2903	3048	-	
90	3500	J8	2840	2990	-	
90	3300	D1	2990	3139	-	
	4000	J8	2899	3051	-	
	4000	D1	3051	3204	-	
	5000	J8	2923	3077	-	
	5000	D1	3077	3231	-	

#### Notes

- 1) The COB is tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature  $(T_J = T_C = 85 \, ^{\circ}C)$ .
- 2) Samsung maintains measurement tolerance of: Luminous flux =  $\pm 7$  %, CRI =  $\pm 1$

## 2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	Р	Н	w	Н	Α	Н	D	N	G	2	5	Υ	Z	W	3	K	0

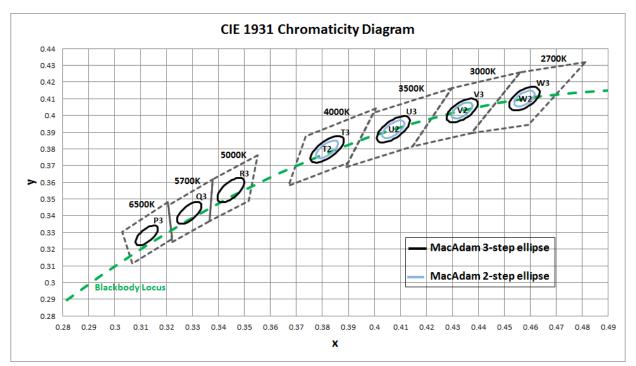
Digit	PKG Information	Code	Specification
1 2 3	Samsung Package High Power	SPH	
4 5	Color	WH	White
6	Product Version	Α	
7 8	Form Factor	HD	СОВ
9	Lens Type	N	No lens
10	Wattage or Model	G	LC026D
11	Internal Code	2	
12	CRI & Sorting Temperature	5	Min. 80 (85°C)
12		7	Min. 90 (85°C)
13 14	Forward Voltage (V)	YZ	31.8~37.5
15	CCT (K)	W V U T R Q	2700K 3000K 3500K 4000K 5000K 5700K 6500K
16	MacAdam Step	3	MacAdam 2-step  MacAdam 3-step
17 18	Luminous Flux	J6 J7 J8 K0 K2 K3 K4	Min. 2600 Min. 2700 Min. 2800 Min. 3000 Min. 3200 Min. 3300 Min. 3400

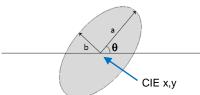
## a) Binning Structure (I<sub>F</sub> = 720 mA, $T_J$ = 85 °C)

CRI (R <sub>a</sub> ) Min.	Nominal CCT (K)	Product Code	V <sub>F</sub> Rank	Color Rank	Flux Rank	Flux Range (Φ <sub>v</sub> , lm)
		SPHWHAHDNG25YZW2K0		W2	K0	3064 ~
	2700 -	SPHWHAHDNG25YZW3K0	YZ	W3	NO	3004 ~
	2700 "	SPHWHAHDNG25YZW2D1	12	W2	D1	3225 ~
		SPHWHAHDNG25YZW3D1		W3	ום	3223 ~
		SPHWHAHDNG25YZV2K2		V2	K2	3220 -
	3000	SPHWHAHDNG25YZV3K2	YZ	V3	- K2 3220 -	3220 ~
	3000	SPHWHAHDNG25YZV2D1	12	V2	D1	3389~
		SPHWHAHDNG25YZV3D1		V3	DI	3309~
	_	SPHWHAHDNG25YZU2K3		U2	K3	3314 ~
	3500	SPHWHAHDNG25YZU3K3	YZ	U3	11.0	3314 ~
80		SPHWHAHDNG25YZU2D1		U2	D1	3488 ~
00		SPHWHAHDNG25YZU3D1		U3	D1	3400 ~
	_	SPHWHAHDNG25YZT2K3		T2	K3	3380 ~
	4000	SPHWHAHDNG25YZT3K3 T3	110	3000		
	4000	SPHWHAHDNG25YZT2D1		T2	D1	3588 ~
		SPHWHAHDNG25YZT3D1		T3	D1	3000
	5000	SPHWHAHDNG25YZR3K4	YZ	R3	K4	3409 ~
		SPHWHAHDNG25YZR3D1	12	11.0	D1	3588 ~
	5700	SPHWHAHDNG25YZQ3K4	YZ	Q3	K4	3409 ~
		SPHWHAHDNG25YZQ3D1	1 4	<b>Q</b> U	D1	3588 ~
	6500	SPHWHAHDNG25YZP3K3	YZ	P3 ·	K3	3380 ~
	0000 "	SPHWHAHDNG25YZP3D1		FΟ	D1	3558 ~

CRI (R <sub>a</sub> ) Min.	Nominal CCT (K)	Product Code	V <sub>F</sub> Rank	Color Rank	Flux Rank	Flux Range (Φ <sub>v</sub> , lm)
		SPHWHAHDNG27YZW2J6		W2	J6	2622 ~
	2700	SPHWHAHDNG27YZW3J6	YZ	W3	30	2022 ~
	2700	SPHWHAHDNG27YZW2D1	12	W2	D1	2760 ~
		SPHWHAHDNG27YZW3D1		W3	DI	2700 ~
		SPHWHAHDNG27YZV2J7		V2	J7	2758 ~
	3000	SPHWHAHDNG27YZV3J7	YZ	V3	J/	2730 ~
	` "	SPHWHAHDNG27YZV2D1	12	V2	D1	2903 ~
90		SPHWHAHDNG27YZV3D1		V3	DI	2903 ~
90		SPHWHAHDNG27YZU2J8		U2	J8	2840 ~
	3500	SPHWHAHDNG27YZU3J8	YZ	U3	36	
	3300	SPHWHAHDNG27YZU2D1		U2	D1	2990 ~
		SPHWHAHDNG27YZU3D1		U3	DI	2990 ~
		SPHWHAHDNG27YZT2J8		T2	J8	2899 ~
	4000	SPHWHAHDNG27YZT3J8	YZ	Т3	Jo	2099 ~
	4000	SPHWHAHDNG27YZT2D1	1 4	T2	D1	3051
		SPHWHAHDNG27YZT3D1		Т3	DΙ	3051 ~
	5000	SPHWHAHDNG27YZR3J8	YZ	R3	J8	2923 ~
		SPHWHAHDNG27YZR3D1	ĭΔ	R3	D1	3077 ~

#### b) Chromaticity Region & Coordinates ( $I_F = 720 \text{ mA}, T_J = 85 \, ^{\circ}\text{C}$ )





MacAdam Ellipse (W2, W3)										
Step	CIE x	CIE y								
2-step	0.4578	0.4101	53.70	0.0054	0.0028					
3-step	0.4578	0.4101	53.70	0.0081	0.0042					

MacAdam Ellipse (V2, V3)										
Step	CIE x	CIE y								
2-step	0.4338	0.403	53.22	0.0056	0.0027					
3-step	0.4338	0.4030	53.22	0.0083	0.0041					

MacAdam Ellipse (U2, U3)										
Step	CIE x	CIE y								
2-step	0.4073	0.3917	54.00	0.0062	0.0028					
3-step	0.4073	0.3917	54.00	0.0093	0.0041					

MacAdam Ellipse (T2, T3)						
Step	CIE x	CIE y				
2-step	0.3818	0.3797	53.72	0.0063	0.0027	
3-step	0.3818	0.3797	53.72	0.0094	0.0040	

MacAdam Ellipse (R3)							
Step	CIE x	CIE y					
3-step	0.3447	0.3553	59.62	0.0082	0.0035		

MacAdam Ellipse (Q3)							
Step CIE x CIE y θ a b							
3-step	0.3287	0.3417	59.0950	0.0075	0.0032		

MacAdam Ellipse (P3)								
Step	Step CIE x CIE y θ a b							
3-step	3-step 0.3123 0.3282 58.5700 0.0067 0.0029							

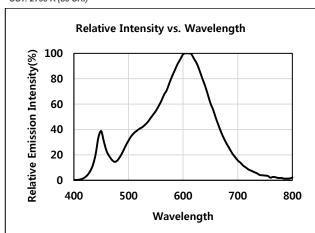
#### Note:

Samsung maintains measurement tolerance of: Cx,  $Cy = \pm 0.005$ 

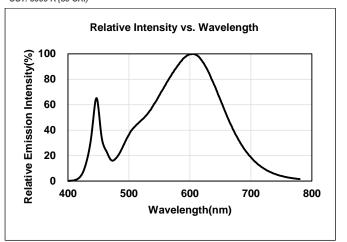
#### 3. Typical Characteristics Graphs

#### a) Spectrum Distribution ( $I_F = 720 \text{ mA}, T_J = 85 \text{ }^{\circ}\text{C}$ )

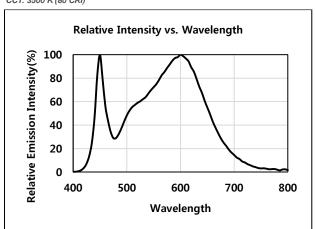
CCT: 2700 K (80 CRI)



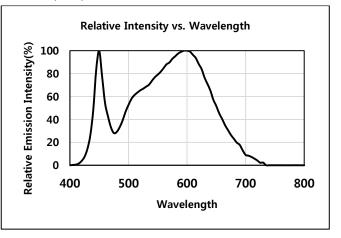
CCT: 3000 K (80 CRI)



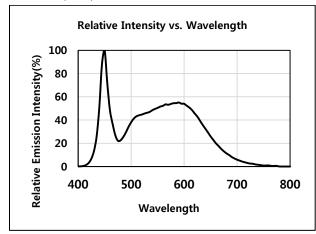
CCT: 3500 K (80 CRI)



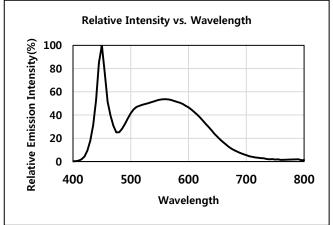
CCT: 4000 K (80 CRI)



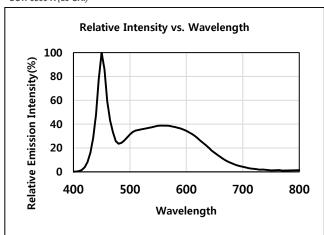
CCT: 5000 K (80 CRI)



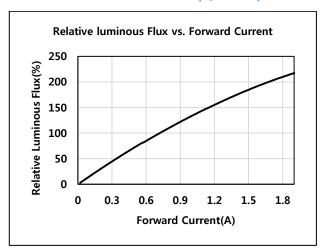
CCT: 5700 K (80 CRI)

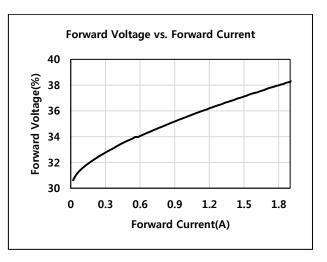


CCT: 6500 K (80 CRI)

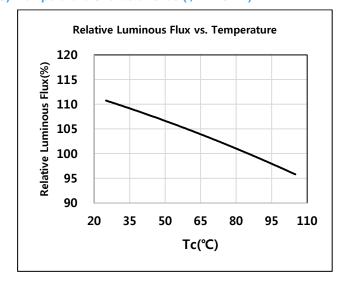


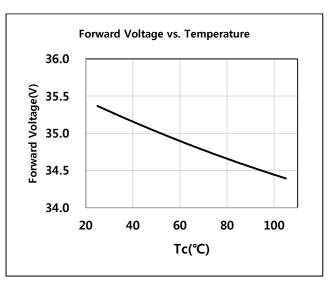
#### b) Forward Current Characteristics (T<sub>J</sub> = 85 °C)



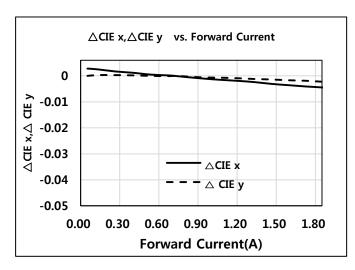


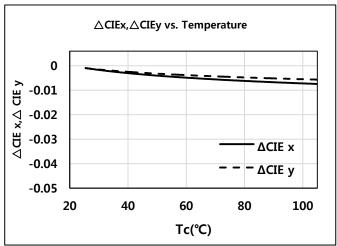
#### C) Temperature Characteristics (I<sub>F</sub> = 720mA)



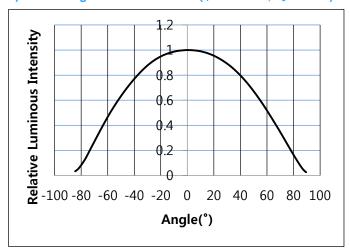


#### d) Color Shift Characteristics ( $T_J = 85$ °C, $I_F = 720$ mA, CRI80+)

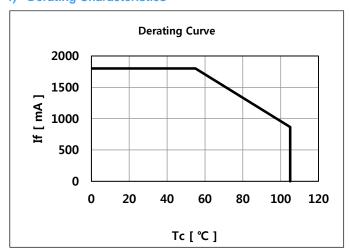




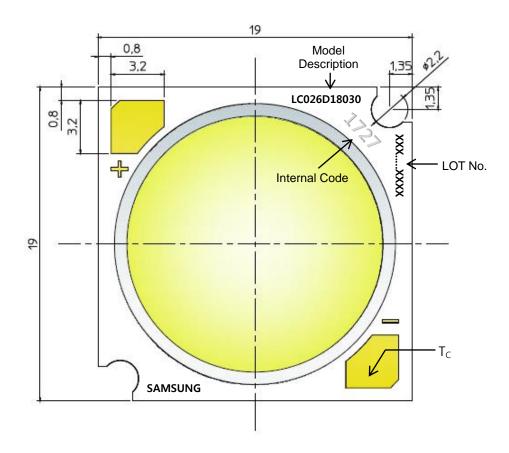
#### e) Beam Angle Characteristics ( $I_F = 720 \text{ mA}, T_J = 85 \text{ }^{\circ}\text{C}$ )

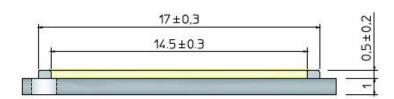


#### f) Derating Characteristics



## 4. Outline Drawing & Dimension





Unit: mm
 Tolerance: ± 0.3 mm

ltem	Dimension	Tolerance	Unit
Length	19.0	±0.15	mm
Width	19.0	±0.15	mm
Height	1.50	±0.30	mm
Light Emitting Surface (LES) Diameter	14.5	±0.30	mm

Note: Denoted product information above is only an example

(LC026D18030: LC026D, CRI80+, 3000K)

## 5. Reliability Test Items & Conditions

#### a) Test Items

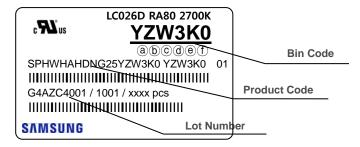
Test Item	Test Condition	Test Hour / Cycle	
High Temperature Humidity Life Test	60 °C, 90 % RH,, DC Derating, I <sub>F</sub>	1000 h	
High Temperature Life Test	85 °C, DC Derating, I <sub>F</sub>	1000 h	
Low Temperature Life Test	-40 $^{\circ}$ C, DC , I <sub>F</sub> = 1290 mA	1000 h	
Pulsed Operating Life Test	55 °C, Pulse width 100 μs, duty cycle 3 %	1000 h	
High Temperature Storage	120 °C	1000 h	
Low Temperature Storage	-40 °C	1000 h	
Temperature Humidity Storage	60 °C, 90% RH	1000h	
Thermal Cycle	-45 °C / 15 min ↔ 125 °C / 15 min temperature change in 5 min	500 cycles	
Temperature Cycle On/Off Test	-40 $^{\circ}$ C / 85 $^{\circ}$ C each 20 min, 30 min transfer power on/off each 5 min, DC Derating, $I_{\rm F}$ = max	100 cycles	
ESD (HBM)	$R_1$ : 10 MΩ $R_2$ : 1.5 kΩ C: 100 pF V: ±2 kV	5 times	
ESD (MM)	$R_{1}$ : $10~M\Omega$ $R_{2}$ : $0~k\Omega$ $C$ : $200~pF$ $V$ : $\pm 0.2~kV$	5 times	
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔ max. frequency 4 min transfer	4 times	
Mechanical Shock Test	1500 g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times	
Sulfur Resistance	25 °C, 75%, H2S 15 ppm	504h	

#### b) Criteria for Judging the Damage

lkerer	Sumbol	Test Condition	Lin	Limit		
ltem	Symbol	(T <sub>c</sub> = 25 °C)	Min.	Max.		
Forward Voltage	$V_{F}$	$I_F = 720 \text{ mA}$	L.S.L. * 0.9	U.S.L. * 1.1		
Luminous Flux	Φν	I <sub>F</sub> = 720 mA	L.S.L * 0.7	U.S.L * 1.3		

#### 6. Label Structure

#### a) Label Structure



Note: Denoted bin code and product code above is only an example (see description on page 5)

#### Bin Code:

(a) (refer to page 11)

©d: Chromaticity bin (refer to page 9-10)

(refer to page 6)

#### b) Lot Number

The lot number is composed of the following characters:



① 3456789 / 1abc / xxxx pcs

: Production site (S: Giheung, Korea, G: Tianjin, China)

② : 4 (LED)

③ : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)

(4) : Year (Z: 2015, A: 2016, B: 2017...)

(1~9, A, B, C)

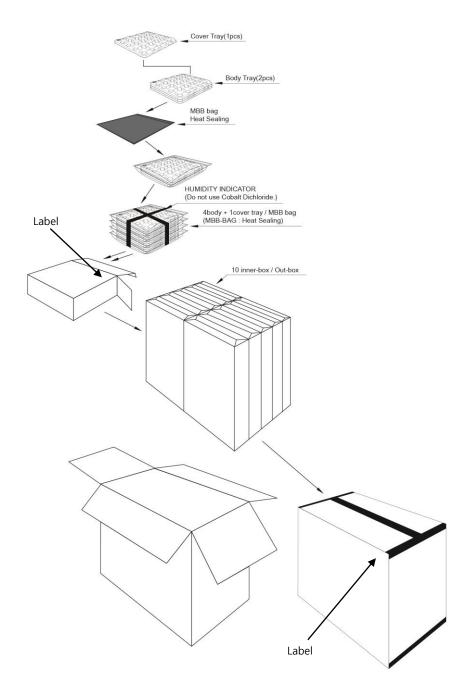
6789 : Day (1~9, A, B~V)

(a)b)C : Product serial number (001 ~ 999)

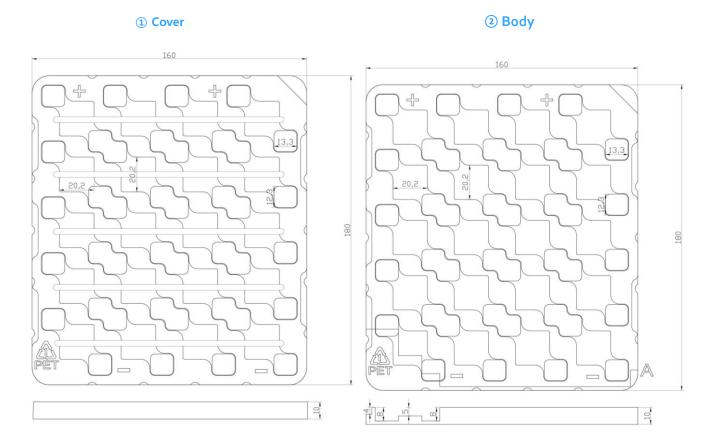
## 7. Packing Structure

	Max. quantity	Dimension(mm)			
Packing material	in pcs of COB	Length	Width	Height	Tolerance
Tray	20	160	180	10	1.0
Aluminum Bag	40(2 trays)	210	241		10
Inner Box	160	230	84	260	2
Outer Box	1600	476	445	272	5

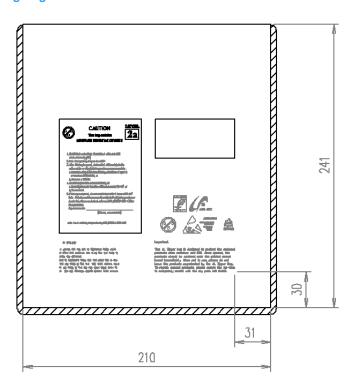
#### a) Packing Structure



#### b) Tray

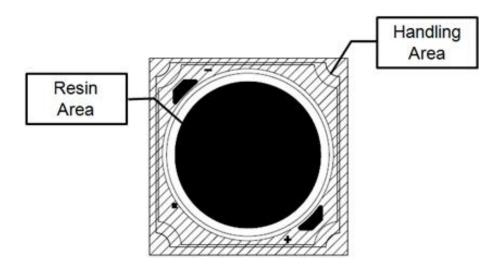


## c) Aluminum Vinyl Packing Bag



#### 8. Precautions in Handling & Use

- This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA
  is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the
  device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- 3) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
  - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
  - b. Stored at <10 % RH
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at 23  $\pm$  5 °C.
- 6) Devices must be baked for 1 hour at  $60 \pm 5$  °C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or antielectrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 8) The thermal management is one of the most critical factors for the LED lighting system. Especially the LED junction temperature should not exceed the absolute maximum rating while operation of LED lighting system.
  - For more information, please refer to Application Note 'Mechanical & Thermal Guide for COB'.
- 9) In case of driving LEDs around the minimum current level (If\_min), chips might exhibit different brightness due to the variation in I-V characteristics of each one. This is normal and does not adversely affect the performance of product.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.



## Legal and additional information.

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